NSN 5961-00-472-3541

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-472-3541

Inclosure Material:

Metal

Overall Length:

0.535 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-63

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.875 inches

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 20.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

60.00 amperes source cutoff current and 15.00 amperes source cutoff current

Power Rating Per Characteristic:

300.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

28009-16601887 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-00-472-3541

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

